

FQA8N100C

FQA8N100C Information

niconductor
ductor Products s, MOSFETs - Single
1000V 8A TO-3P
3
ventory/lead time, please contact
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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



FQA8N100C Specifications

Manufacturer Part Number	FQA8N100C
Manufacturer	Fairchild/ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-3P-3, SC-65-3
Series	QFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1000V
Current - Continuous Drain (Id) @ 25°C	8A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	70nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3220pF @ 25V
Vgs (Max)	$\pm 30 V$
FET Feature	-
Power Dissipation (Max)	225W (Tc)
Rds On (Max) @ Id, Vgs	1.45 Ohm @ 4A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-3PN
Package / Case	TO-3P-3, SC-65-3
	Report errors?

FQA8N100C Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE GUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

FQA8N100C Payment Methods Image: Im

If you have any question about FQA8N100C, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com